

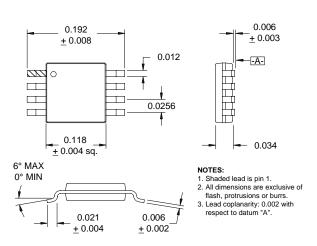
W-CDMA AND CDMA UPCONVERTER/ BPSK MODULATOR

Typical Applications

- W-CDMA Systems
- PCS/Cellular CDMA Systems
- PHS 1500/WLAN 2400 Systems
- General Purpose Upconverter
- BPSK Modulation
- Micro-Cell PCS Base Stations

Product Description

The RF2638 is a complete upconverter designed for cellular, PCS and W-CDMA applications. This device may also be used to directly BPSK modulate a carrier. The unit operates at 3.0V and is designed as part of the RFMD PCS/Cellular CDMA and W-CDMA Chip Sets.



Package Style: MSOP-8

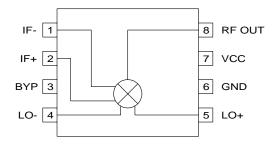
Optimum Technology Matching® Applied

Si BJT

☐ GaAs HBT

☐ GaAs MESFET

☐ Si Bi-CMOS ☐ SiGe HBT ☐ Si CMOS



Functional Block Diagram

Features

- Supports Dual Mode Operation
- +10dBm Output IP3 (1950MHz)
- +13dBm Output IP3 (830MHz)
- Single 3.0V Power Supply
- Miniature 8-Pin Package
- Double-Balanced Mixer

Ordering Information

RF2638 W-CDMA and CDMA Upconverter/ BPSK Modulator RF2638 PCBA-PCS/CEL Fully Assembled Evaluation Board F2638 PCBA-DO Fully Assembled Evaluation Board F2638 PCBA-W Fully Assembled Evaluation Board

 RF Micro Devices, Inc.
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RF2638

Absolute Maximum Ratings

Parameter		Rating	Unit			
	Supply Voltage	-0.5 to +5.0	V_{DC}			
	Input RF Power	+3	dBm			
	Operating Ambient Temperature	-30 to +80	°C			
	Storage Temperature	-30 to +150	°C			



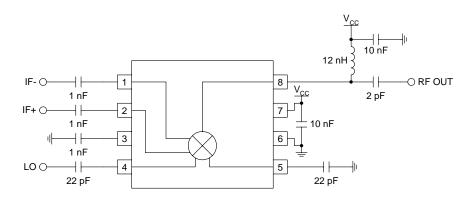
RF Micro Devices believes the furnished information is correct and accurate at the time of this printing. However, RF Micro Devices reserves the right to make changes to its products without notice. RF Micro Devices does not assume responsibility for the use of the described product(s).

Doromotor	Specification		11:4	Condition		
Parameter	Min.	Тур.	Max.	Unit	Condition	
Overall					T=25°C, V _{CC} =3.0V	
RF Output Frequency Range		500 to 2500		MHz		
Spurious Product Rejection		30		dBc	Referenced to RF output	
Cellular			T=25°C, V _{CC} =3.0 V, LO=960 MHz @-3dBm,			
Conversion Gain	-1	-0.5		dB	IF=130MHz@-13dBm RF _{OUT} =830MHz	
Conversion Gain	-2.2	-0.5		dВ	RF _{OUT} =836MHz (Dual-Output board)	
Noise Figure	-2.2	14		dВ	RF _{OUT} =830MHz	
Output IP3		+13		dBm	P _{IN} =-13dBm per Tone, RF out=830MHz	
Output IF3		713		ubili	T=25°C, V _{CC} =3.0V,	
PCS					LO=1750MHz@-3dBm.	
					IF=130MHz@-13dBm	
Conversion Gain	-3.0	-1.5		dB	RF _{OUT} =1880MHz	
	-3.5	-2.5		dB	RF _{OUT} =1880MHz (Dual-Output board)	
Noise Figure		15		dB	RF _{OUT} =1880MHz	
Output IP3	+7	+11		dBm	P _{IN} =-13dBm per Tone, RF out=1880MHz	
					T=25°C, V _{CC} =3.0V,	
W-CDMA					LO=2330MHz@-3dBm,	
AODD	50	F-7	50	-ID-	IF=380MHz@-13dBm	
ACPR Conversion Gain	-58 -2.0	-57 -1.0	-56 0	dBc dB	RF _{OUT} =1950MHz	
Noise Figure	13	14	15	dB	RF _{OUT} =1950MHz	
Output IP3	+8	+10	13	dBm	P _{IN} =-13dBm per Tone, RF _{OUT} =1950MHz	
Max OIP3	70	710	11	dBm	FIN=130Bill bel Tolle, KI OUT=1930WI12	
IF Input			11	ubili		
IF Frequency	DC	130/380	500	MHz		
Differential Input Impedance	220	260	300	Ω	IF=130MHz	
IF to RF Output Isolation		30		dB		
IF to LO Isolation		30		dB		
LO Input						
LO Frequency Range		300 to 2700		MHz		
LO Level	40	-6 to 0		dBm		
LO to RF Output Leakage	-18 -15	-25 -17		dBm dBm	At Callular hand, high aids injection	
	-15	-1/		dBm	At Cellular band, high side injection (Dual-Output board)	
	-14	-15		dBm	At PCS band, low side injection	
RF to LO Isolation		30		dB	(Dual-Output board)	
LO Input VSWR		2:1		QD.	50Ω	
Power Supply						
Voltage	2.7	3.0	3.3	V		
Current Consumption		25		mA		

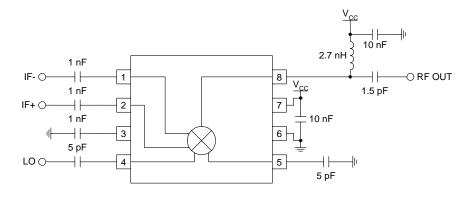
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Pin	Function	Description	Interface Schematic
1	IF-	Balanced IF input pin. This pin is internally DC-biased and should be DC-blocked if connected to a device with a DC level present. For single-ended input operation, one pin is used as an input and the other IF input is AC-coupled to ground. The balanced, input impedance is 260Ω .	BIAS 130 Ω 130 Ω 1F-
2	IF+	Same as pin 1, except complementary input.	See pin 1.
3	ВҮР	Bypass pin for internal bias circuitry. Bypass with a 1nF capacitor.	BYP — W
4	Balanced LO input pin. This pin is internally DC-biased and should be DC-blocked if connected to a device with a DC level present. For single ended input operation, one pin is used as an input and the other LO input is AC-coupled to ground.		LO- LO+
5	LO+	Same as pin 4, except complementary input.	See pin 4.
6	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
7	VCC	Supply voltage pin. External bypassing is required. External RF, LO, and IF bypassing is required. The trace length between the pin and the bypass capacitors should be minimized. The ground side of the bypass capacitors should connect immediately to ground plane.	
8	RF OUT	RF output pin.	300 Ω O RF OUT

Application Schematic 836MHz

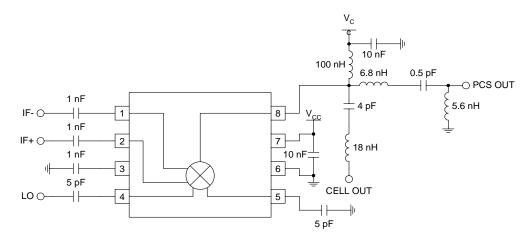


Application Schematic 1880MHz

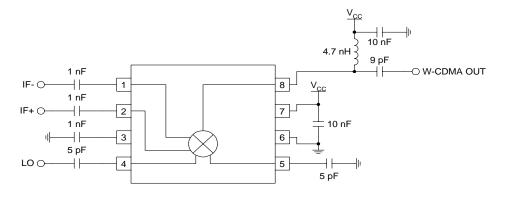


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Application Schematic Dual-Band Output (836MHz/1880MHz)

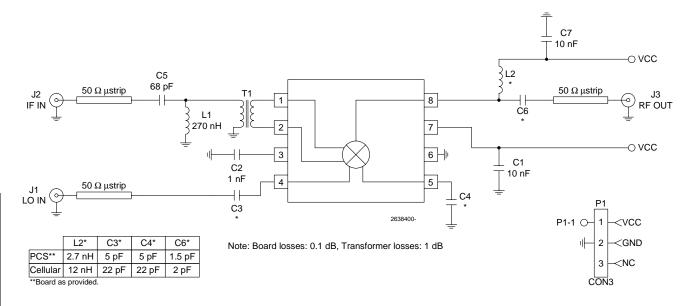


Application Schematic W-CDMA (1950MHz)

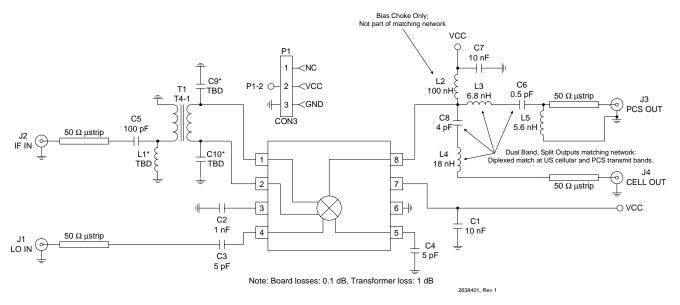


Evaluation Board Schematic - PCS/Cellular RF = 1880MHz, IF = 130MHz

(Download Bill of Materials from www.rfmd.com.)

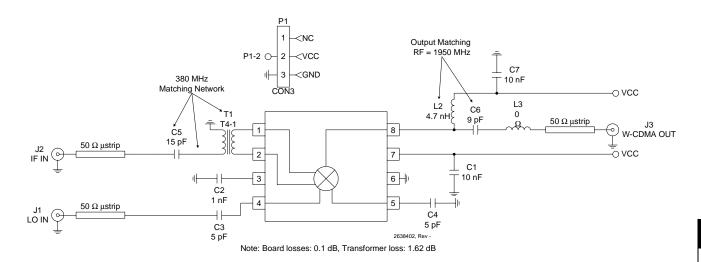


Evaluation Board Schematic - Dual Output Cellular Out=836MHz, PCS Out=1880MHz, IF=130MHz



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Evaluation Board Schematic - W-CDMA RF = 1950MHz, IF = 380MHz

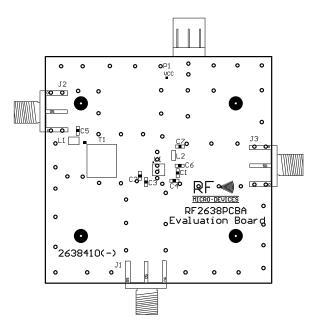


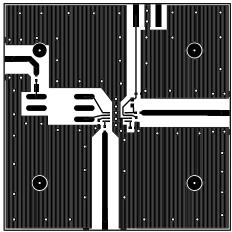
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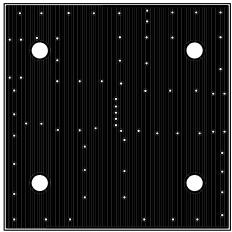
Evaluation Board Layout PCS/Cellular

Board Size 2.0" x 2.0"

Board Thickness 0.031", Board Material FR-4





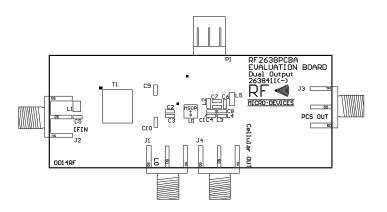


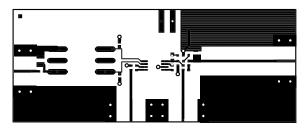
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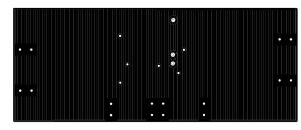
Evaluation Board Layout Dual Output

Board Size 2.5" x 1.0"

Board Thickness 0.060", Board Material FR-4, Multi-Layer (Intermediate layers (Ground Plane and Power Plane [V_{CC1}]) are not shown.)





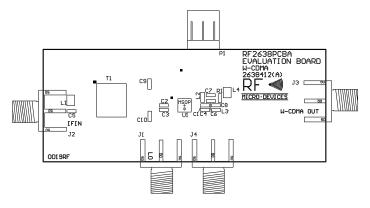


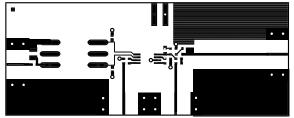
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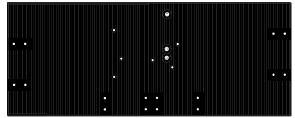
Evaluation Board Layout W-CDMA

Board Size 2.5" x 1.0"

Board Thickness 0.060", Board Material FR-4, Multi-Layer (Intermediate layers (Ground Plane and Power Plane [$V_{\rm CC1}$]) are not shown.)







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